

FORM PTO-1449				Atty. Docket No. XA-9485A	Appln. No.		
<u>LIST OF DOCUMENTS CITED BY APPLICANT</u>							
				Applicant Masaya MURANAKA et al.			
				Filing Date HEREWITH	Group		
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Examiner Initial		Document Number	Date	Name	Class	Sub-class	Filing Date
TB	AA	6,560,725 B1	05/2003	Longwell et al.	714	54	
	AB	6,065,146 A	05/2000	Bosshart, Patrick	714	754	
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TB	AJ	11-213659	08/06/99	Japan			Abstract
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OTHER (including author, title, date, pertinent pages, etc.)							
TB	AP	Mano, T.; Yamada, J.; Inoue, J.; Nakajima, S.; Circuit Techniques For A VLSI Memory, IEEE Journal of Solid-State Circuits, Volume: 18 Issue: 5, October 1983, Pages 463-470					
	AQ						
	AR						
Examiner <i>/Timothy Bonura/</i>				Date Considered 10/05/2006			
EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.							